

## N-Ch 20V Fast Switching MOSFETs

- ★ 100% EAS Guaranteed
- ★ Green Device Available
- ★ Super Low Gate Charge
- ★ Excellent CdV/dt effect decline
- ★ Advanced high cell density Trench technology

### Product Summary



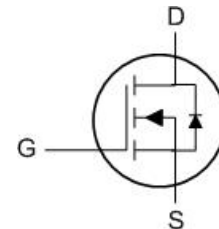
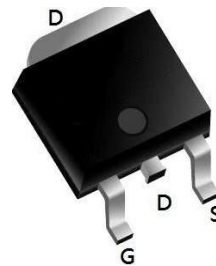
| BVDSS | RDS(on) | ID  |
|-------|---------|-----|
| 20V   | 8 mΩ    | 40A |

### Description

The UD40N02 is the high cell density trenched N-ch MOSFETs, which provide excellent RDS(on) and gate charge for most of the synchronous buck converter applications.

The UD40N02 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

### TO252 Pin Configuration



### Absolute Maximum Ratings

| Symbol                                | Parameter                                                    | Rating     | Units |
|---------------------------------------|--------------------------------------------------------------|------------|-------|
| V <sub>DS</sub>                       | Drain-Source Voltage                                         | 20         | V     |
| V <sub>GS</sub>                       | Gate-Source Voltage                                          | ±20        | V     |
| I <sub>D</sub> @T <sub>C</sub> =25°C  | Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> | 40         | A     |
| I <sub>D</sub> @T <sub>C</sub> =100°C | Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> | 20         | A     |
| I <sub>DM</sub>                       | Pulsed Drain Current <sup>2</sup>                            | 120        | A     |
| EAS                                   | Single Pulse Avalanche Energy <sup>3</sup>                   | 23         | mJ    |
| I <sub>AS</sub>                       | Avalanche Current                                            | 21         | A     |
| P <sub>D</sub> @T <sub>C</sub> =25°C  | Total Power Dissipation <sup>4</sup>                         | 25         | W     |
| T <sub>STG</sub>                      | Storage Temperature Range                                    | -55 to 150 | °C    |
| T <sub>J</sub>                        | Operating Junction Temperature Range                         | -55 to 150 | °C    |

### Thermal Data

| Symbol           | Parameter                                     | Typ. | Max. | Unit |
|------------------|-----------------------------------------------|------|------|------|
| R <sub>θJC</sub> | Thermal Resistance Junction-Case <sup>1</sup> | ---  | 7.5  | °C/W |

## N-Ch 20V Fast Switching MOSFETs

### Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise specified)

| Symbol                                                 | Parameter                                                 | Test Condition                                                                               | Min. | Typ. | Max. | Units |
|--------------------------------------------------------|-----------------------------------------------------------|----------------------------------------------------------------------------------------------|------|------|------|-------|
| Off Characteristic                                     |                                                           |                                                                                              |      |      |      |       |
| V <sub>(BR)DSS</sub>                                   | Drain-Source Breakdown Voltage                            | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                                                   | 20   | -    | -    | V     |
| I <sub>DSS</sub>                                       | Zero Gate Voltage Drain Current                           | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V,                                                   | -    | -    | 1.0  | μA    |
| I <sub>GSS</sub>                                       | Gate to Body Leakage Current                              | V <sub>DS</sub> =0V, V <sub>GS</sub> =±12V                                                   | -    | -    | ±100 | nA    |
| On Characteristics                                     |                                                           |                                                                                              |      |      |      |       |
| V <sub>GS(th)</sub>                                    | Gate Threshold Voltage                                    | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                     | 0.5  | 0.75 | 1.2  | V     |
| R <sub>DS(on)</sub>                                    | Static Drain-Source on-Resistance<br><small>note3</small> | V <sub>GS</sub> =4.5V, I <sub>D</sub> =15A                                                   | -    | 8    | 11.2 | mΩ    |
|                                                        |                                                           | V <sub>GS</sub> =2.5V, I <sub>D</sub> =10A                                                   | -    | 11.7 | 17.5 |       |
| Dynamic Characteristics                                |                                                           |                                                                                              |      |      |      |       |
| C <sub>iss</sub>                                       | Input Capacitance                                         | V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,<br>f=1.0MHz                                       | -    | 1000 | -    | pF    |
| C <sub>oss</sub>                                       | Output Capacitance                                        |                                                                                              | -    | 182  | -    | pF    |
| C <sub>rss</sub>                                       | Reverse Transfer Capacitance                              |                                                                                              | -    | 164  | -    | pF    |
| Q <sub>g</sub>                                         | Total Gate Charge                                         | V <sub>DS</sub> =10V, I <sub>D</sub> =15A,<br>V <sub>GS</sub> =4.5V                          | -    | 15   | -    | nC    |
| Q <sub>gs</sub>                                        | Gate-Source Charge                                        |                                                                                              | -    | 2    | -    | nC    |
| Q <sub>gd</sub>                                        | Gate-Drain(“Miller”) Charge                               |                                                                                              | -    | 5.2  | -    | nC    |
| Switching Characteristics                              |                                                           |                                                                                              |      |      |      |       |
| t <sub>d(on)</sub>                                     | Turn-on Delay Time                                        | V <sub>DS</sub> =10V,<br>I <sub>D</sub> =15A, R <sub>GEN</sub> =3Ω,<br>V <sub>GS</sub> =4.5V | -    | 9    | -    | ns    |
| t <sub>r</sub>                                         | Turn-on Rise Time                                         |                                                                                              | -    | 25   | -    | ns    |
| t <sub>d(off)</sub>                                    | Turn-off Delay Time                                       |                                                                                              | -    | 37   | -    | ns    |
| t <sub>f</sub>                                         | Turn-off Fall Time                                        |                                                                                              | -    | 14   | -    | ns    |
| Drain-Source Diode Characteristics and Maximum Ratings |                                                           |                                                                                              |      |      |      |       |
| I <sub>S</sub>                                         | Maximum Continuous Drain to Source Diode Forward Current  |                                                                                              | -    | -    | 40   | A     |
| I <sub>SM</sub>                                        | Maximum Pulsed Drain to Source Diode Forward Current      |                                                                                              | -    | -    | 120  | A     |
| V <sub>SD</sub>                                        | Drain to Source Diode Forward Voltage                     | V <sub>GS</sub> =0V, I <sub>S</sub> =30A                                                     | -    | -    | 1.2  | V     |

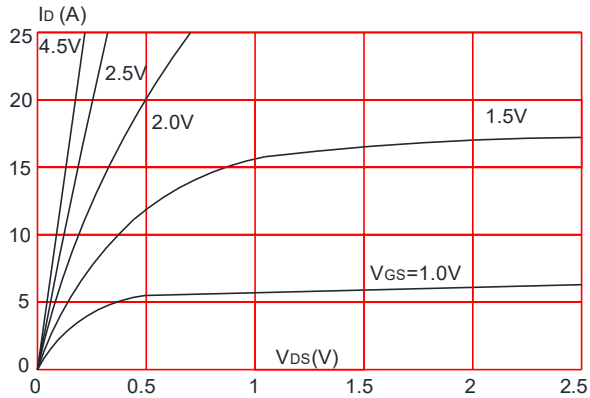
Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. EAS condition: T<sub>J</sub>=25°C, V<sub>DD</sub>=10V, V<sub>G</sub>=4.5V, L=0.5mH, R<sub>G</sub>=25Ω, I<sub>AS</sub>=9.6A

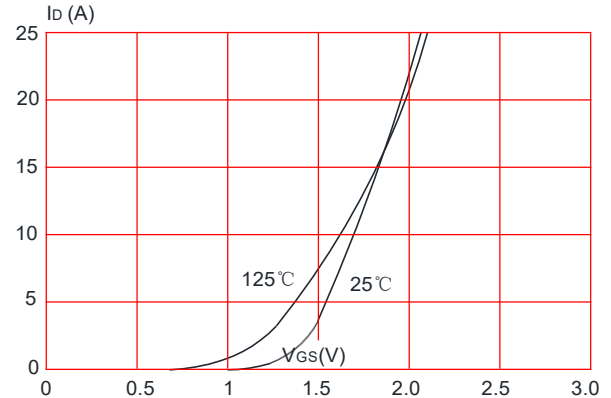
3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%

## Typical Performance Characteristics

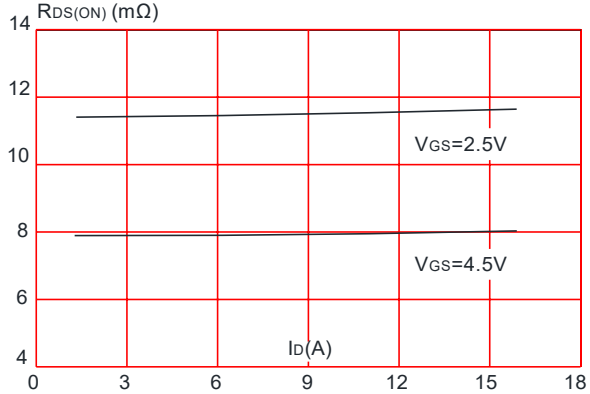
**Figure 1:** Output Characteristics



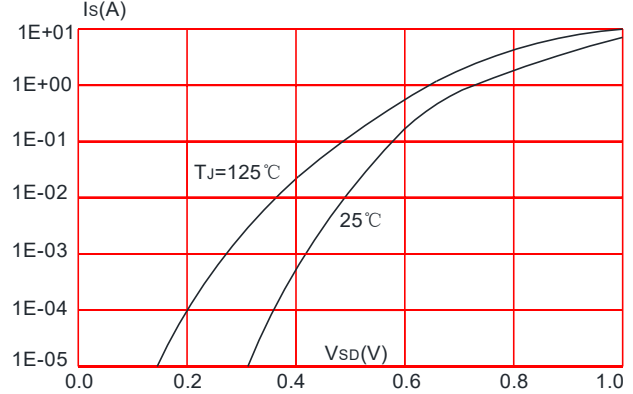
**Figure 2:** Typical Transfer Characteristics



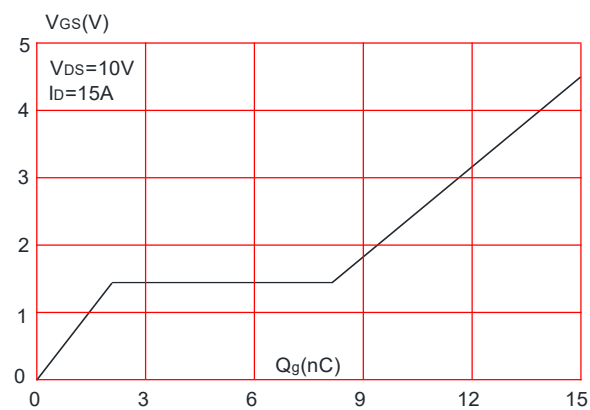
**Figure 3:** On-resistance vs. Drain Current



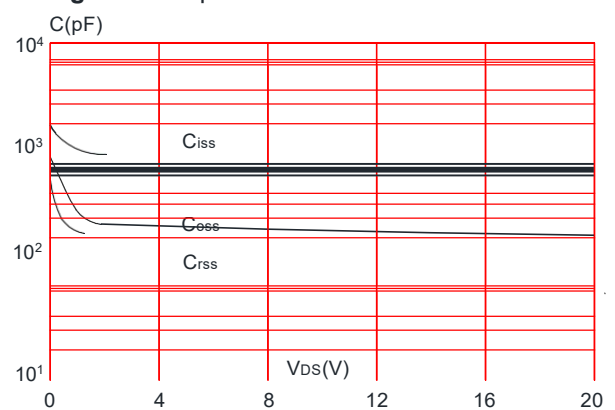
**Figure 4:** Body Diode Characteristics



**Figure 5:** Gate Charge Characteristics

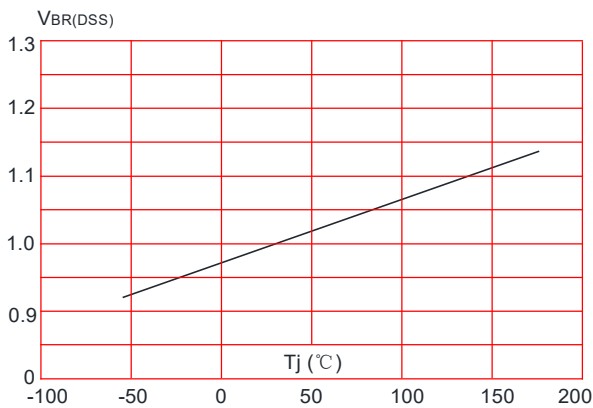


**Figure 6:** Capacitance Characteristics

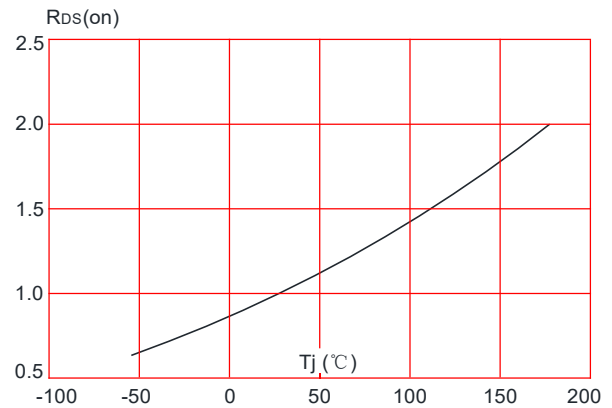


N-Ch 20V Fast Switching MOSFETs

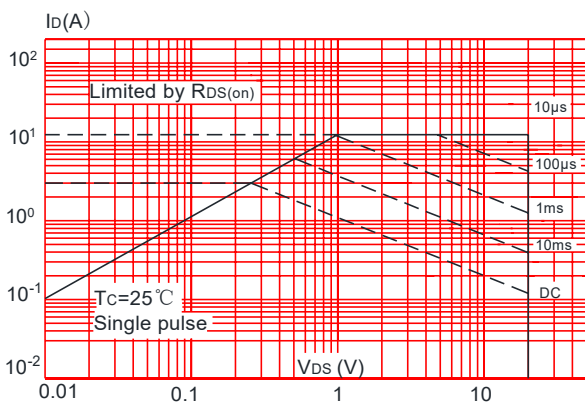
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



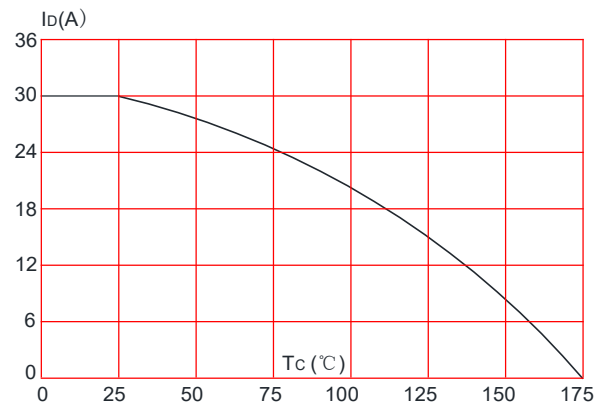
**Figure 8:** Normalized on Resistance vs. Junction Temperature



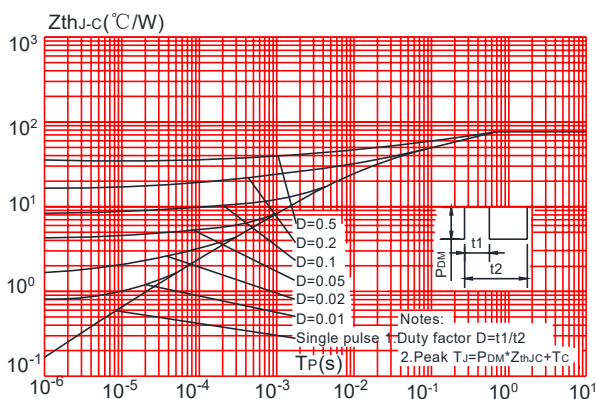
**Figure 9:** Maximum Safe Operating Area



**Figure 10:** Maximum Continuous Drain Current vs. Case Temperature

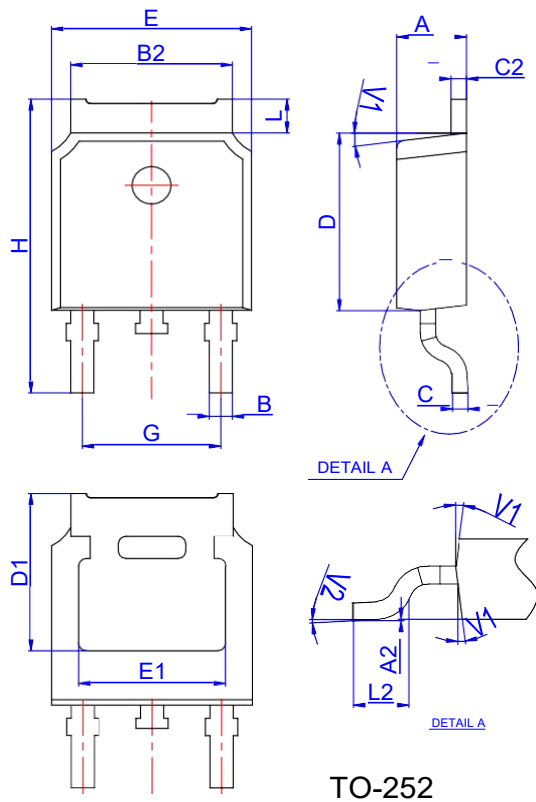


Maximum Effective Transient Thermal Impedance, Junction-to-Case



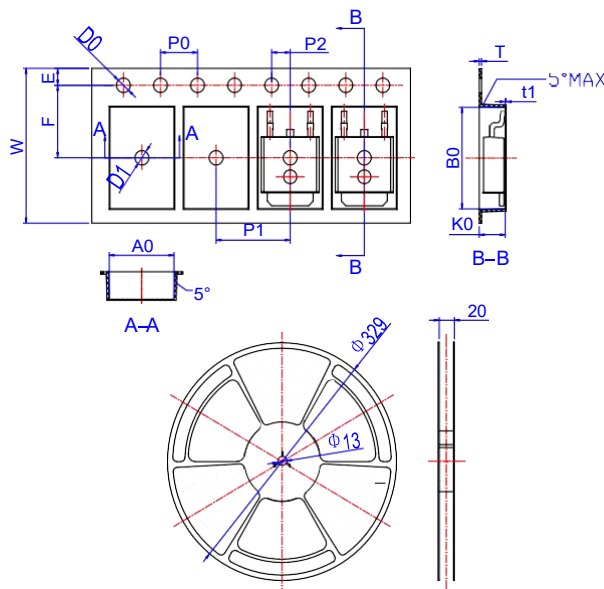
## N-Ch 20V Fast Switching MOSFETs

### Package Mechanical Data-TO-252-4R



| Ref. | Dimensions  |      |       |          |      |       |
|------|-------------|------|-------|----------|------|-------|
|      | Millimeters |      |       | Inches   |      |       |
|      | Min.        | Typ. | Max.  | Min.     | Typ. | Max.  |
| A    | 2.10        |      | 2.50  | 0.083    |      | 0.098 |
| A2   | 0           |      | 0.10  | 0        |      | 0.004 |
| B    | 0.66        |      | 0.86  | 0.026    |      | 0.034 |
| B2   | 5.18        |      | 5.48  | 0.202    |      | 0.216 |
| C    | 0.40        |      | 0.60  | 0.016    |      | 0.024 |
| C2   | 0.44        |      | 0.58  | 0.017    |      | 0.023 |
| D    | 5.90        |      | 6.30  | 0.232    |      | 0.248 |
| D1   | 5.30REF     |      |       | 0.209REF |      |       |
| E    | 6.40        |      | 6.80  | 0.252    |      | 0.268 |
| E1   | 4.63        |      |       | 0.182    |      |       |
| G    | 4.47        |      | 4.67  | 0.176    |      | 0.184 |
| H    | 9.50        |      | 10.70 | 0.374    |      | 0.421 |
| L    | 1.09        |      | 1.21  | 0.043    |      | 0.048 |
| L2   | 1.35        |      | 1.65  | 0.053    |      | 0.065 |
| V1   |             | 7°   |       |          | 7°   |       |
| V2   | 0°          |      | 6°    | 0°       |      | 6°    |

### Reel Specification-TO-252-4R



| Ref. | Dimensions  |       |       |        |       |       |
|------|-------------|-------|-------|--------|-------|-------|
|      | Millimeters |       |       | Inches |       |       |
|      | Min.        | Typ.  | Max.  | Min.   | Typ.  | Max.  |
| W    | 15.90       | 16.00 | 16.10 | 0.626  | 0.630 | 0.634 |
| E    | 1.65        | 1.75  | 1.85  | 0.065  | 0.069 | 0.073 |
| F    | 7.40        | 7.50  | 7.60  | 0.291  | 0.295 | 0.299 |
| D0   | 1.40        | 1.50  | 1.60  | 0.055  | 0.059 | 0.063 |
| D1   | 1.40        | 1.50  | 1.60  | 0.055  | 0.059 | 0.063 |
| P0   | 3.90        | 4.00  | 4.10  | 0.154  | 0.157 | 0.161 |
| P1   | 7.90        | 8.00  | 8.10  | 0.311  | 0.315 | 0.319 |
| P2   | 1.90        | 2.00  | 2.10  | 0.075  | 0.079 | 0.083 |
| A0   | 6.85        | 6.90  | 7.00  | 0.270  | 0.271 | 0.276 |
| B0   | 10.45       | 10.50 | 10.60 | 0.411  | 0.413 | 0.417 |
| K0   | 2.68        | 2.78  | 2.88  | 0.105  | 0.109 | 0.113 |
| T    | 0.24        |       | 0.27  | 0.009  |       | 0.011 |
| t1   | 0.10        |       |       | 0.004  |       |       |
| 10P0 | 39.80       | 40.00 | 40.20 | 1.567  | 1.575 | 1.583 |